

General Description

The MAX4734 is a low on-resistance, low-voltage, 4channel CMOS analog multiplexer that operates from a single 1.6V to 3.6V supply. This device has fast switching speeds (ton = 25ns, toff = 20ns max), handles Rail-to-Rail® analog signals, and consumes less than 4µW of quiescent power. The MAX4734 has breakbefore-make switching.

When powered from a 3V supply, the MAX4734 features low 0.8Ω (max) on-resistance (R_{ON}), with 0.2Ω (max) RoN matching and 0.1Ω RoN flatness. The digital logic input is 1.8V CMOS compatible when using a single 3V supply.

The MAX4734 is available in space-saving 12-pin QFN (3mm x 3mm) and 10-pin µMAX packages.

Applications

Power Routing

Battery-Powered Systems

Audio and Video Signal Routing

Low-Voltage Data-Acquisition Systems

Communications Circuits

PCMCIA Cards

Cellular Phones

Modems

Hard Drives

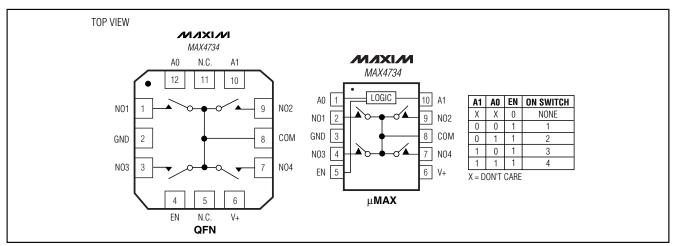
Features

- **♦ Low Ron**
 - 0.8Ω (max) (3V Supply) 2Ω (max) (1.8V Supply)
- ♦ 0.1Ω (max) Ron Flatness (3V Supply)
- ♦ 1.6V to 3.6V Single-Supply Operation
- ♦ Available in QFN (3mm x 3mm) Package
- ♦ High-Current Handling Capacity (150mA Continuous)
- ♦ 1.8V CMOS-Logic Compatible (3V Supply)
- ◆ Fast Switching: toN = 25ns, toFF = 20ns

Ordering Information

PART	TEMP RANGE	PIN-PACKAGE
MAX4734EUB	-40°C to +85°C	10 μMAX
MAX4734EGC	-40°C to +85°C	12 QFN (3mm x 3mm)

Pin Configurations/Functional Diagrams/Truth Table



Rail-to-Rail is a registered trademark of Nippon Motorola, Ltd.

MIXIM

Maxim Integrated Products 1

ABSOLUTE MAXIMUM RATINGS

Voltages Referenced to GND	
V+, A_, EN	0.3V to +4V
COM, NO_ (Note 1)	0.3V to $(V + + 0.3V)$
Continuous Current COM, NO	±150mA
Continuous Current (all other pins)	±20mA
Peak Current COM, NO_	
(pulsed at 1ms 10% duty cycle)	±300mA

Continuous Power Dissipation ($T_A = +70^\circ$	°C)	
10-Pin μMAX (derate 5.6mW/°C above	+70°C)	444mW
12-Pin QFN (derate 14.7mW/°C above	+70°C)	.1176mW
Operating Temperature Range	40°C	to +85°C
Maximum Junction Temperature		+150°C
Storage Temperature Range		
Lead Temperature (soldering, 10s)		+300°C

Note 1: Signals on COM or NO_ exceeding V+ or GND are clamped by internal diodes. Limit forward current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—Single 3V Supply

 $(V+ = 2.7V \text{ to } 3.6V, V_{IH} = 1.4V, V_{IL} = 0.5V, T_A = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise specified.}$ Typical values are at V+ = 3.0V, T_A = +25°C.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS
ANALOG SWITCH	•						
Analog Signal Range	V _{COM} , V _{NO} _			0		V+	V
0.5		V+ = 2.7V,	+25°C		0.6	0.8	Ω
On-Resistance (Note 4)	R _{ON}	ICOM = 100mA, V _{NO} _ = 1.5V	T _{MIN} to T _{MAX}			1	
On-Resistance Match		V+ = 2.7V, I _{COM} = 100mA, V _{NO} _ = 1.5V	+25°C		0.1	0.2	Ω
Between Channels (Notes 4, 5)	ΔR _{ON}		T _{MIN} to T _{MAX}			0.3	
On-Resistance Flatness (Note 6)		V+ = 2.7V, ICOM_ = 100mA, VNO_ = 1V, 1.5V, 2V	+25°C		0.05	0.1	Ω
	R _{FL} AT(ON)		T _{MIN} to T _{MAX}			0.2	
NO_ Off-Leakage Current (Note 7)		V+ = 3.6V,	+25°C	-1	±0.002	+1	^
	INO_(OFF)	V _{COM} = 0.3V, 3.3V, V _{NO} = 3.3V, 0.3V	T _{MIN} to T _{MAX}	-5		+5	· nA
COM Off-Leakage Current (Note 7)	ICOM(OFF)	V+ = 3.6V, V _{COM} = 0.3V, 3.3V, V _{NO} = 3.3V, 0.3V	+25°C	-1	±0.002	+1	
			T _{MIN} to T _{MAX}	-5		+5	nA
COM On-Leakage Current (Note 7)	ICOM(ON)	V+ = 3.6V, V _{COM} = 3.3V, 0.3V, V _{NO} = 3.3V, 0.3V, or floating	+25°C	-2	±0.002	+2	
			T _{MIN} to T _{MAX}	-10		+10	nA

ELECTRICAL CHARACTERISTICS—Single 3V Supply (continued)

 $(V+=2.7V \text{ to } 3.6V, V_{IH}=1.4V, V_{IL}=0.5V, T_A=T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise specified.}$ Typical values are at $V+=3.0V, T_A=+25^{\circ}C.)$ (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS
SWITCH DYNAMIC CHARACTERISTICS							
Turn-On Time	ton	$V_{NO_{-}} = 1.5V$, $R_{L} = 50\Omega$, $C_{L} = 35pF$,	+25°C		20	25	ns
Turn on time	1011	Figure 1	T _{MIN} to T _{MAX}			30	110
Turn-Off Time		$V_{NO_{-}} = 1.5V,$ $R_{L} = 50\Omega, C_{L} = 35pF,$	+25°C		15	20	
Turri-On Time	toff	Figure 1	T _{MIN} to T _{MAX}			25	ns
Break-Before-Make (Note 8)	toou	$V_{NO} = 1.5V,$ $R_{L} = 50\Omega, C_{L} = 35pF,$	+25°C		5		no
break-before-iviake (Note o)	tBBM	Figure 2	T _{MIN} to T _{MAX}	1			ns
Charge Injection	Q	$V_{GEN} = 0$, $R_{GEN} = 0$, $C_L = 1.0$ nF, Figure 3	+25°C		60		рС
NO_ Off-Capacitance	Coff	f = 1MHz, Figure 4	+25°C		33		рF
COM Off-Capacitance	C _{COM} (OFF)	f = 1MHz, Figure 4	+25°C		117		рF
COM On-Capacitance	C _{COM} (ON)	f = 1MHz, Figure 4	+25°C		171		рF
-3dB On-Channel Bandwidth	BW	Signal = 0, $R_{IN} = R_{OUT} = 50\Omega$, $C_L = 5pF$, Figure 5			90		MHz
Off-Isolation (Note 9)	V _{ISO}	$f = 1MHz$, $V_{COM} = 1V_{P-P}$, $R_L = 50\Omega$, $C_L = 5pF$, Figure 5	+25°C		-56		dB
Crosstalk (Note 10)	VCT	$f = 1MHz$, $V_{COM} = 1V_{P-P}$, $R_L = 50\Omega$, $C_L = 5pF$, Figure 5	+25°C		-56		dB
Total Harmonic Distortion	THD	$f = 20$ Hz to 20 kHz, $V_{COM} = 2V_{P-P}$, $R_L = 32\Omega$	+25°C		0.018		%
LOGIC INPUT (A_, EN)							
Input Logic High	VIH			1.4			V
Input Logic Low	V _{IL}					0.5	V
Input Leakage Current	I _{IN}	V _{EN} = 0 or 3.6V, V _A _ = 0 or 3.6V		-1	0.005	+1	μΑ
POWER SUPPLY							
Power-Supply Range	V+			1.6		3.6	V
Positive Supply Current	I+	V+ = 3.6V, V _{EN} , A_ = 0 or V+, all channels on or off			0.004	1	μΑ

ELECTRICAL CHARACTERISTICS—Single 1.8V Supply

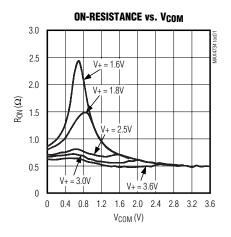
 $(V+ = 1.8V, V_{IH} = 1.0V, V_{IL} = 0.4V, T_A = T_{MIN}$ to T_{MAX} , unless otherwise specified. Typical values are at $T_A = +25$ °C.) (Notes 2, 3)

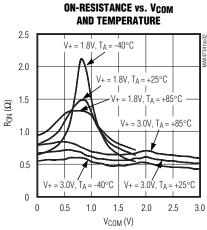
PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS
ANALOG SWITCH							
Analog Signal Range	V _{COM} , V _{NO} _			0		V+	V
On-Resistance	Pou	I _{COM} _ = 10mA,	+25°C		1.5	2	Ω
On-nesistance	R _{ON}	V _{NO} _ = 1V	T _{MIN} to T _{MAX}			3	22
SWITCH DYNAMIC CHARACTE	RISTICS						
Turn-On Time	ton	$V_{NO} = 1V,$ $R_L = 50\Omega, C_L = 35pF,$	+25°C		25	30	ns
		Figure 1	T _{MIN} to T _{MAX}			35	
Turn-Off Time	toff	$V_{NO_{-}} = 1V,$ $R_{L} = 50\Omega, C_{L} = 35pF,$	+25°C		18	25	- ns
Turri on Time	1OFF	Figure 1	T _{MIN} to T _{MAX}			28	
	t _{BBM}	$V_{NO_} = 1V$, $R_L = 50\Omega$, $C_L = 35pF$, Figure 2	+25°C		7		- ns
Break-Before-Make (Note 8)			T _{MIN} to T _{MAX}	1			
Charge Injection	Q	V _{GEN} = 0, R _{GEN} = 0, C _L = 1nF, Figure 3	+25°C		35		рС
Off-Isolation (Note 9)	V _{ISO}	$f = 1MHz, V_{NO_}$ $= 1V_{P-P}, R_L = 50\Omega,$ $C_L = 5pF, Figure 5$	+25°C		-56		dB
Crosstalk (Note 10)	VCT	$ f = 1 \text{MHz, V}_{\text{COM}} = 1 \text{Vp-p,} $ $ R_{\text{L}} = 50 \Omega, $ $ C_{\text{L}} = 5 \text{pF, Figure 5} $	+25°C		-56		dB
LOGIC INPUT (A_, EN)							
Input Logic High	VIH			1			V
Input Logic Low	VIL					0.4	V
Input Leakage Current	I _{IN}	V _{EN} = 0 or 3.6V, V _A _ = 0 or 3.6V				1	μΑ

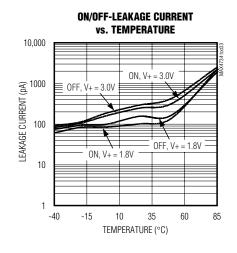
- **Note 2:** The algebraic convention, where the most negative value is a minimum and the most positive value is a maximum, is used in this data sheet.
- Note 3: -40°C specifications are guaranteed by design.
- Note 4: R_{ON} and ΔR_{ON} matching specifications for QFN packaged parts are guaranteed by design.
- **Note 5:** $\Delta R_{ON} = R_{ON(MAX)} R_{ON(MIN)}$.
- **Note 6:** Flatness is defined as the difference between the maximum and the minimum value of on-resistance as measured over the specified analog signal ranges.
- Note 7: Leakage parameters are 100% tested at hot temperature and guaranteed by correlation at room temperature.
- Note 8: Guaranteed by design.
- **Note 9:** Off-Isolation = $20log_{10}(V_{COM}/V_{NO_-})$, V_{COM} = output, V_{NO_-} = input to off switch.
- Note 10: Between two switches.

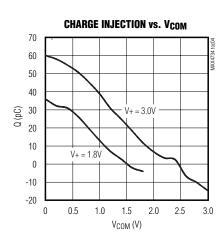
Typical Operating Characteristics

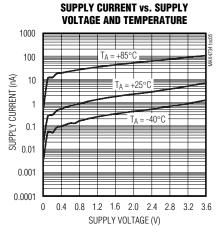
 $(T_A = +25^{\circ}C, \text{ unless otherwise noted.})$

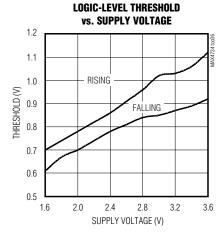


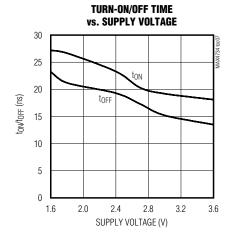


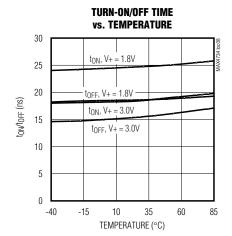






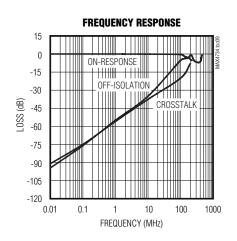


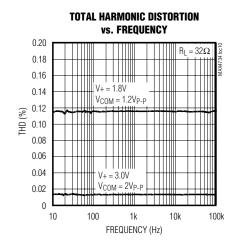




Typical Operating Characteristics (continued)

 $(T_A = +25^{\circ}C, \text{ unless otherwise noted.})$





Pin Description

PIN		NAME	FUNCTION	
μМΑХ	QFN	NAME	FUNCTION	
1	12	A0	Address 0 Input	
2	1	NO1	Analog Switch 1—Normally Open Terminal	
3	2	GND	Ground	
4	3	NO3	Analog Switch 3—Normally Open Terminal	
5	4	EN	Enable Logic Input	
6	6	V+	Positive-Supply Voltage Input	
7	7	NO4	Analog Switch 4—Normally Open Terminal	
8	8	COM	Analog Switch Common Terminal	
9	9	NO2	Analog Switch 2—Normally Open Terminal	
10	10	A1	Address 1 Input	
_	5, 11	N.C.	No Connection	

Detailed Description

The MAX4734 is a low 0.8Ω max (at V+ = 2.7V) on-resistance, low-voltage, 4-channel CMOS analog multiplexer that operates from a 1.6V to 3.6V single supply. CMOS switch construction allows switching analog signals that range from GND to V+.

When powered from a 2.7V supply, the 0.8 Ω max RoN allows high continuous currents to be switched in a variety of applications.

Applications Information

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings, because stresses beyond the listed ratings can cause permanent damage to the devices. Always sequence V+ on first, followed by NO_ or COM.

Although it is not required, power-supply bypassing improves noise margin and prevents switching noise propagation from the V+ supply to other components. A 0.1µF capacitor, connected from V+ to GND, is adequate for most applications.

Logic Inputs

The MAX4734 logic inputs can be driven up to 3.6V regardless of the supply voltage. For example, with a 1.8V supply, A_ and EN may be driven low to GND and high to 3.6V. Driving A_ and EN rail-to-rail minimizes power consumption.

Analog Signal Levels

Analog signals that range over the entire supply voltage (V+ to GND) can be passed with very little change in onresistance (see *Typical Operating Characteristics*). The switches are bidirectional, so the NO_ and COM_ pins can be used as either inputs or outputs.

Layout

High-speed switches require proper layout and design procedures for optimum performance. Reduce stray inductance and capacitance by keeping traces short and wide. Ensure that bypass capacitors are as close to the device as possible. Use large ground planes where possible.

Test Circuits/Timing Diagrams

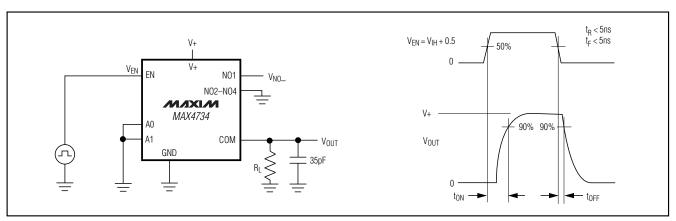


Figure 1. Switching Time

Test Circuits/Timing Diagrams (continued)

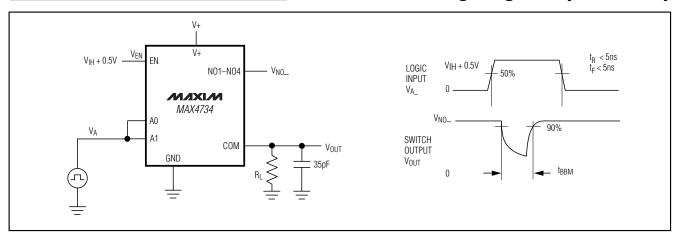


Figure 2. Break-Before-Make Interval

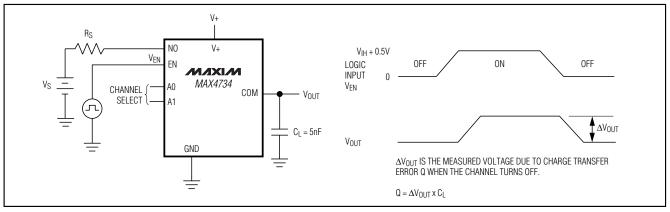


Figure 3. Charge Injection

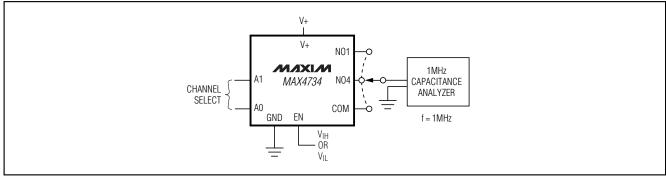


Figure 4. Channel Off/On-Capacitance

Test Circuits/Timing Diagrams (continued)

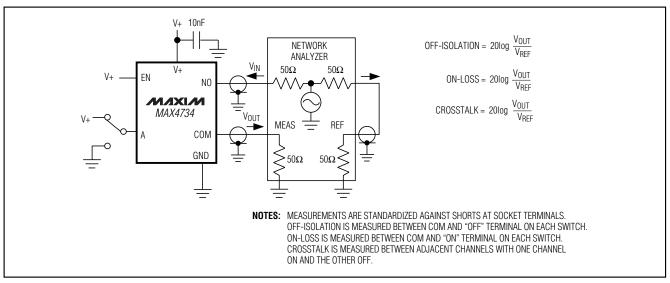


Figure 5. Off-Isolation/On-Channel/Crosstalk Bandwidth

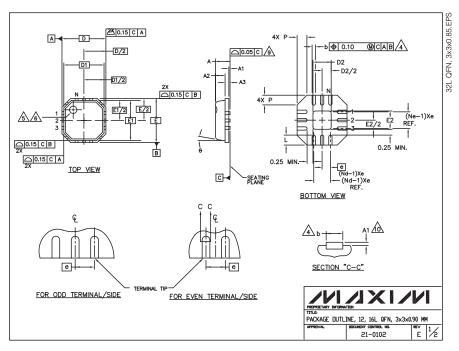
Chip Information

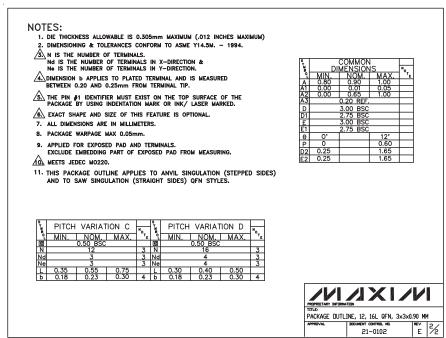
TRANSISTOR COUNT: 379

PROCESS: CMOS

Package Information

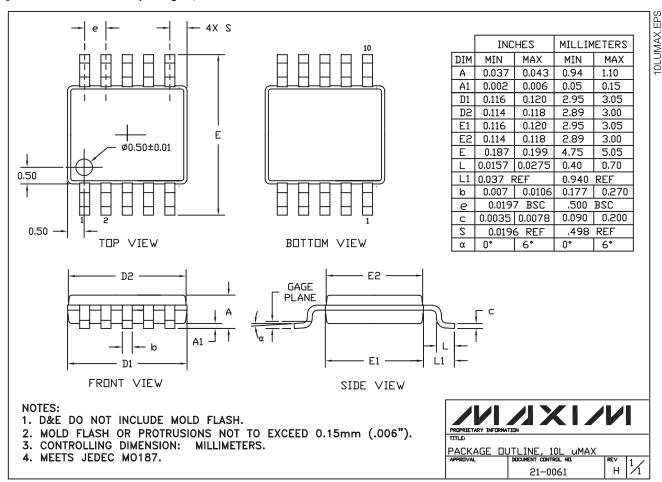
(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to **www.maxim-ic.com/packages**.)





Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to **www.maxim-ic.com/packages**.)



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